# 2SC5938

FOR LOW FREQUENCY AMPLIFY APPLICATION
SILICON NPN EPITAXIAL TYPE

## DESCRIPTION

ISAHAYA 2SC5938 is a super mini package resin sealed silicon NPN epitaxial transistor for muting and switching. application

## FEATURE

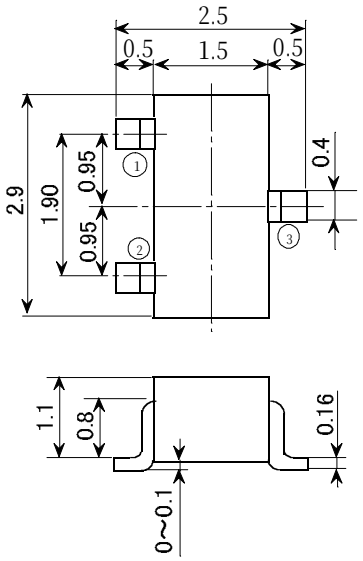
- High Emitter to Base voltage VEBO=50V
- High Reverse hFE
- Low ON RESISTANCE. RON=1Ω
- Small packege for mounting

## APPLICATION

For muting, switching application

## OUTLINE DRAWING

Unit : mm




TERMINAL CONNECTOR

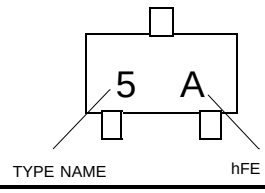
① : BASE
② : EMITTER
③ : COLLECTOR

EIJA:SC-59

MAXIMUM RATINGS (Ta=25°C)

| Symbol | Parameter | Ratings | Unit |
|---|---|---|---|
| VCBO | Collector to Base voltage | 50 | V |
| VCEO | Collector to Emitter voltage | 12 | V |
| VEBO | Emitter to Base voltage | 50 | V |
| I C | Collector current | 200 | mA |
| PC | Collector dissipation | 150 | mW |
| Tj | Junction temperature | +125 | °C |
| Tstg | Storage temprature | -55 ～ +125 | °C |

MARKING




ELECTRICAL CHARACTERISTICS (Ta=25°C)

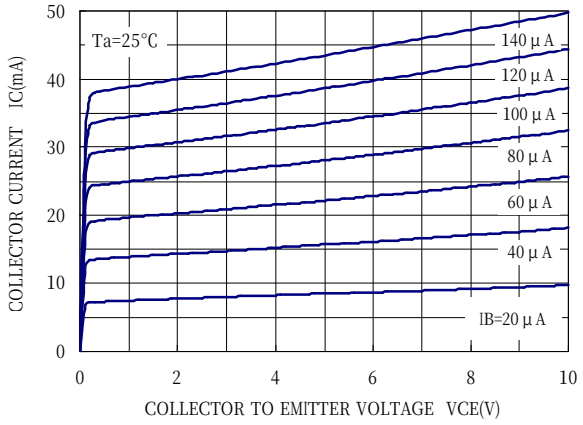
| Symbol | Parameter | Test conditions | Limits | | | Unit |
|---|---|---|---|---|---|---|
| | | | Min | Typ | Max | |
| I CBO | Collector cut off current | VCB=50V, I E=0mA | | | 0.1 | μA |
| I EBO | Emitter cut off current | VEB=50V, IC=0mA | | | 0.1 | μA |
| hFE | DC forward current gain | VCE=2V, I C=4mA | 200 | | 1200 | |
| VCE(sat) | C to E saturation voltage | I C=30mA, I B=3mA | | 30 | | mV |
| fT | Gain bandwidth product | VCE=6V, I C=4mA | | 30 | | MHz |
| Cob | Collector output capacitance | VCB=10V, I E=0mA, f=1MHz | | 5.0 | | pF |

| Item | A | B |
|---|---|---|
| hFE | 200 to 700 | 350 to 1200 |
| Marking | 5A | 5B |

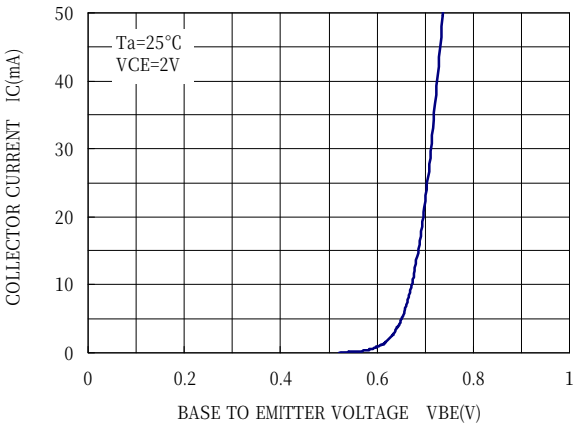
# 2SC5938

FOR LOW FREQUENCY AMPLIFY APPLICATION
SILICON NPN EPITAXIAL TYPE

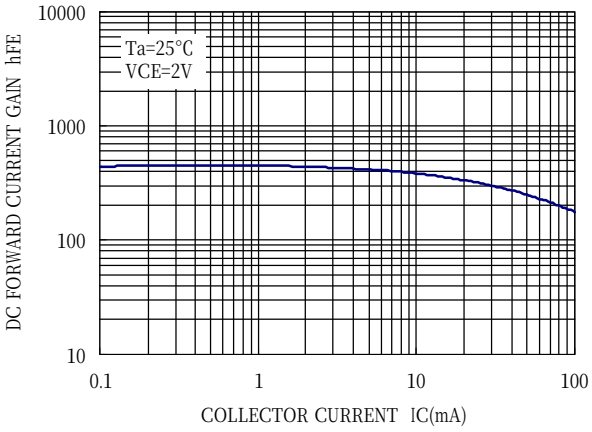
COMMON EMITTER OUTPUT



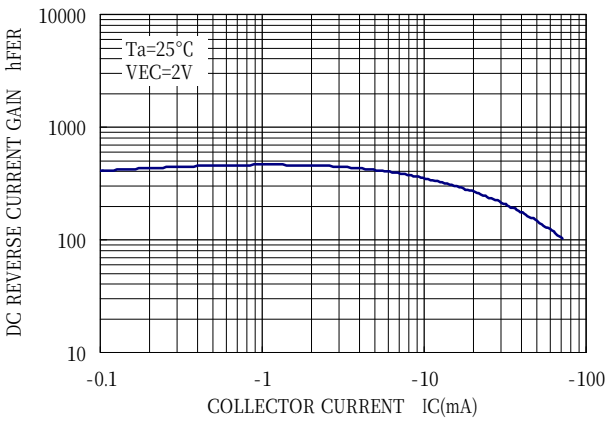

COMMON EMITTER TRANSFER



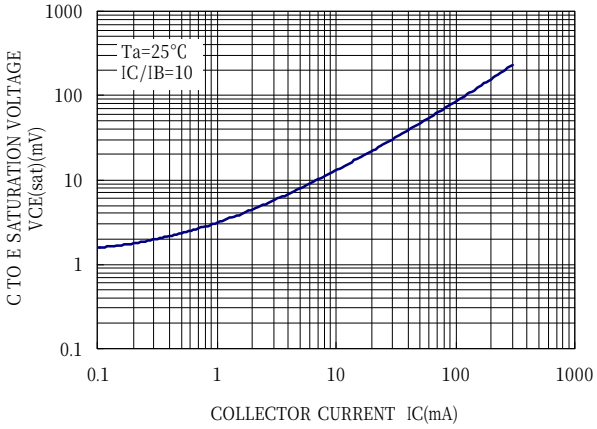

DC FORWARD CURRENT GAIN
VS. COLLECTOR CURRENT



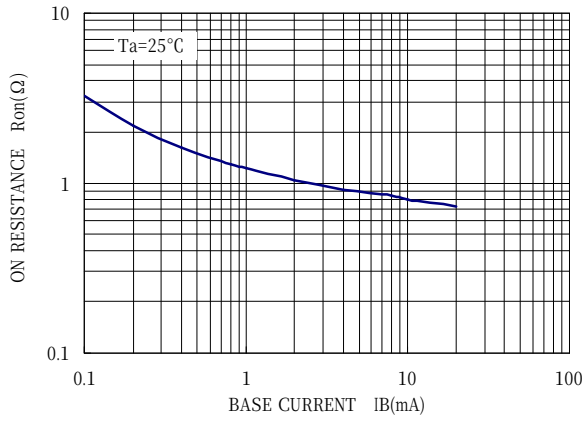

DC REVERSE CURRENT GAIN
VS. COLLECTOR CURRENT




COLLECTOR TO EMITTER SATURATION VOLTAGE
VS.COLLECTOR CURRENT



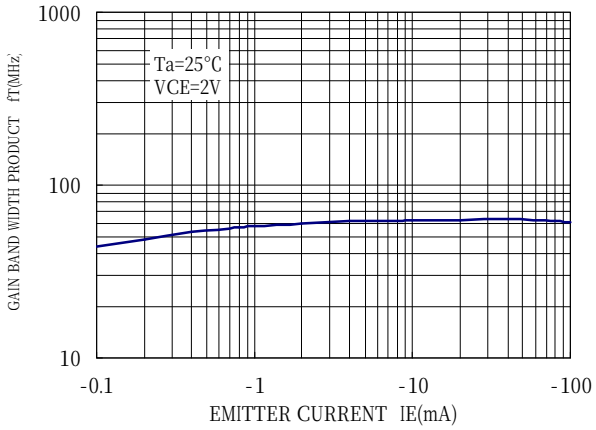

ON RESISTANCE VS. BASE CURRENT



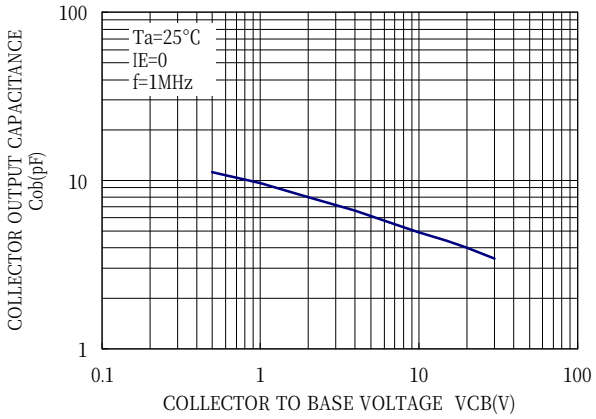
# 2SC5938

FOR LOW FREQUENCY AMPLIFY APPLICATION
SILICON NPN EPITAXIAL TYPE

GAIN BAND WIDTH PRODUCT VS.
EMITTER CURRENT




COLLECTOR OUTPUT CAPACITANCE
VS. COLLECTOR TO BASE VOLTAGE



ISAHAYA ELECTRONICS CORPORATION

*Marketing division, Marketing planning department*

6-41 Tsukuba, Isahaya, Nagasaki, 854-0065 Japan

**Keep safety first in your circuit designs!**

·ISAHAYA Electronics Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (1) placement of substitutive, auxiliary, (2) use of non-farmable material or (3) prevention against any malfunction or mishap.

**Notes regarding these materials**

·These materials are intended as a reference to our customers in the selection of the ISAHAYA products best suited to the customer's application; they don't convey any license under any intellectual property rights, or any other rights, belonging ISAHAYA or third party.

·ISAHAYA Electronics Corporation assumes no responsibility for any damage, or infringement of any third party's rights, originating in the use of any product data, diagrams, charts or circuit application examples contained in these materials.

·All information contained in these materials, including product data, diagrams and charts, represent information on products at the time of publication of these materials, and are subject to change by ISAHAYA Electronics Corporation without notice due to product improvements or other reasons. It is therefore recommended that customers contact ISAHAYA Electronics Corporation or an authorized ISAHAYA products distributor for the latest product information before purchasing product listed herein.

·ISAHAYA Electronics Corporation products are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact ISAHAYA electronics corporation or an authorized ISAHAYA products distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.

·The prior written approval of ISAHAYA Electronics Corporation is necessary to reprint or reproduce in whole or in part these materials.

·If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination. Any diversion or re-export contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited.

·Please contact ISAHAYA Electronics Corporation or authorized ISAHAYA products distributor for further details on these materials or the products contained therein.

Jan.2003